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Capillary condensation and adsorption of binary mixtures

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Abstract

The adsorption of equimolar binary mixtures of hydrogen-carbon dioxide, hydrogen-methane and methane-carbon dioxide in porous material models is determined by Grand Canonical Monte Carlo simulations. The material models have an adsorbent surface similar to that of nanofibers with a herringbone structure. Our main result, which is relevant for hydrogen purification and carbon dioxide capture, is that the adsorption selectivities calculated for the mixtures can differ significantly from those deduced from simulations of the adsorption of pure gases, in particular when one of the adsorbed gases presents a capillary condensation induced by confinement within the pore network. A comparison of our data is also made with theoretical models used in the literature for predicting the properties of the mixture adsorption.

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I. INTRODUCTION

The main application of the adsorption in porous materials is the separation of gaseous mixtures into their different components [1] and, in future, the capture of greenhouse gas emission [2]. The efficiency of these purification processes depends on the interactions and sizes of the component molecules which determine the ability of each molecule type to be adsorbed in the pore network of materials. The carbonaceous porous materials are an adsorbent class often used in the gas separation. Among these materials, the carbon nanofibers (CNF) or graphite nanofibers (GNF) have been actively studied in particular as a possible material for the hydrogen gas storage [3–9].

Numerous theoretical works on the gas adsorption in carbonaceous materials have been published in the literature [10–22]. They studied the properties of material models where the adsorbent surface was constituted by graphite basal planes or the external and internal surfaces of single or multi-walled carbon nanotubes. Most of these works concerned the adsorption of pure gases, but some have been devoted to that of mixtures [23–25]. In the present work, by using Grand Canonical Monte Carlo (GCMC) simulations, we study the adsorption of gas mixtures on a model of GNF with a herringbone structure. The simulations allow to compute the selectivity, a quantity characterizing the purification capacity of a porous material. In addition to the theoretical determination of adsorption properties of GNF, our aim is to contribute to the improvement of purification processes by showing that a physical interpretation of the selectivities of binary mixtures can be made from the density profiles computed for the mixture components and pure gases inside a typical pore of a porous material.

The simulations have been realized for equimolar mixtures of H_2 and CO_2 , H_2 and CH_4 , and CH_4 and CO_2 . This relative concentration has been chosen because it is to the order of magnitude of that present in the industrial purification processes. It seems adequate for obtaining a good estimate of the selectivities for mixtures where the relative concentrations have similar values, i.e 30-50%.

Section II is devoted to the description of the GNF model and that of molecular and atomic potentials used in the simulations. In section III, the simulation results are presented, discussed, and compared to those of theoretical models used to predict the properties of the pure gas and mixture adsorption. In the conclusion, we stress on the importance of the

 CO_2 capillary condensation in the studied adsorption processes when they take place at a temperature and pressure close to 300 K and 5.0 MPa.

II. MODEL AND INTERACTIONS

In GCMC simulations, the adsorption processes of physisorption type result from van der Waals interactions between the adsorbed fluids and adsorbent materials. They are described at a microscopic scale and the adsorption properties of a specific porous material are obtained from those of nanopores considered as being mainly present in the material pore network.

In this work, a porous material constituted by GNF is studied. The GNF are supposed to have a herringbone structure made up by graphene sheets tilted with respect to the fiber axis [26]. The GNF adsorbent surfaces are formed by the rows of carbon atoms located at the external edges of the graphene sheets. These carbon atoms have pending bonds which can be functionalized by chemical groups. Inside the material model, the nanopores are supposed to be slits delimited by stacks of graphite planes, separated from another by a distance of 0.34 nm, where the external carbon atoms are functionalized with H atoms [27]. Then, the adsorbing walls of the pores are constituded by CH groups. The superficial density of these adsorbing sites is 12.0 per nm². It is smaller than that of adsorbing sites (C atoms) of graphite basal planes equal to 38.0 per nm². But, the lower superficial density of adsorbing CH groups is compensated by their stronger van der Waals interaction with adsorbed gases compared to that of C atoms located in graphite planes (cf. Table I below).

In the simulation volume or simulation cell, the two stacks defining the slit, disposed parallel to the oy axis, are separated by a distance d between their CH groups. The stacks are periodically replicated in the y and z directions and the slit, formed by two stacks and the space between these stacks, replicated in the x direction. The stacks are tilted with respect to the z axis, supposed parallel to the fiber axis, by 30 degrees. The extent of graphite planes in the x direction corresponds to 3 hexagons of carbon atoms and is equal to $D \simeq 1.1$ nm including the CH group size on the edges. It has been chosen in taking into account the fast decreasing of the van der Waals interactions between gas molecules and carbon atoms located inside the stacks. A larger width of the stacks in the x direction would not contribute significantly to increase the gas molecule adsorption on the GNF external surfaces. As a consequence of the chosen values of D, the specific surface of the adsorbent model, defined

as the surface of the adsorbent per unit of adsorbent mass is equal $1032 \text{ m}^2/\text{gr}$. With this geometry, the adsorption in the slit pore should correspond to a quasi maximal value of the ratios: mass and excess mass of adsorbed gas on adsorbent mass, ratios which, muliplied by a factor of 100, are defined in the literature as weight per cent and excess weight per cent of a porous material [28–30]. The slit widths d, considered in the simulations, are, respectively, equal to 1.0 nm, 2.5 nm and 5.0 nm. Each stack is formed by 16 graphite planes and the total number of C atoms present in the cells is equal to 3264 and that of CH groups equal to 1088.

Fig. 1 presents a three-dimensional view of the pore model and a molecule typical configuration of an adsorbed H_2 - CO_2 mixture in equilibrium with a bulk equimolar H_2 - CO_2 mixture at a temperature of 293 K and total pressure of 10.0 MPa.

The intermolecular van der Waals interactions of gases and those between gas molecules and adsorbent are represented by Lennard-Jones (LJ) potentials. For H_2 and CH_4 molecules and CH groups, the united-atom approximation [31] is used and an only LJ potential, located at the center of mass, represents the van der Waals interactions. For CO_2 , the van der Waals interactions are described by 3 LJ potentials located at the positions of the C and O atoms [32, 33]. In addition to these LJ interactions, H_2 and CO_2 molecules have a linear electric quadrupole, described by a neutral distribution of 3 charges located, respectively, for H_2 at the positions of protons (charge q) and center of mass (charge q) and for CO_2 at those of the O atoms (charge q) and C atom (charge q).

The LJ potentials $v_{LJ}(r) = 4\epsilon[(\sigma/r)^{12} - (\sigma/r)^6]$ are defined by the parameters ϵ and σ . The values of these parameters, those of the charges associated to the electric quadrupoles of H_2 and CO_2 and the positions l of the charges q, relative to the center of mass along the molecule axis, are given in Table I. The parameters of LJ potentials for the C atoms and CH groups [31] present in the GNF are also given in Table I. The parameters of the LJ cross interactions between atoms of different molecule species and between these atoms and GNF are obtained from the Berthelot's rules summarized by the relations $\epsilon_{\alpha\beta} = \sqrt{\epsilon_{\alpha} \epsilon_{\beta}}$ and $\sigma_{\alpha\beta} = (\sigma_{\alpha} + \sigma_{\beta})/2$. where ϵ_{α} , ϵ_{β} , σ_{α} and σ_{β} denote the LJ parameters of gas molecules and LJ parameters associated to GNF atoms and chemical groups.

III. RESULTS AND DISCUSSIONS

In a GCMC simulation, the composition of a mixture adsorbed in a porous medium is obtained by determining the equilibrium state between the adsorbed mixture and a bulk mixture with a given composition, pressure and temperature. Such a computation is realized by performing a GCMC simulation in a simulation cell, filled with an adsorbent sample, at a temperature and chemical potentials of mixture components equal to those existing in the bulk mixture.

At room temperature and pressures below 10.0 MPa, considered in this work, the species chemical potentials μ_i^b (*i* index denotes H_2 , CO_2 or CH_4 molecule) in a bulk mixture at fixed temperature, pression and composition can be reasonably estimated from the approximation of perfect mixtures [1]. However, we have determined the values of μ_i^b by GCMC simulations performed in an empty simulation cell. The values of μ_i^b are modified until the wanted total pressure P_T and composition of the bulk mixture are obtained. The total pressure of mixtures and the partial pressures P_i of each species having a density d_B^i are computed by using the virial theorem:

$$P_T = kT \sum_{i} d_B^i + \frac{1}{3V} < \sum_{i} \sum_{k} \mathbf{R}_k^i \cdot \mathbf{F}_k^i > + \frac{\langle \sum_{i} \sum_{k} Q_k^i \rangle}{3V}.$$
 (1)

 \mathbf{R}_k^i is the position of the center of mass of the molecule k of species i and \mathbf{F}_k^i the total force acting on this molecule. Q_k^i is the contribution to the pressure of the molecular electrical quadrupole which is proportional to the quadrupolar energy [34]. < ... > denotes a GC average. The partial pressures P_i of the species i correspond to the contributions labelled with a index i in the sums \sum_i of Eq. 1.

The adsorption properties of the GNF pore model, described above, have been computed for pure gases and mixtures from GCMC runs of 12×10^6 Monte-Carlo elementary moves performed after preliminary runs of 8×10^6 MC moves which allowed to reach the equilibrium state of the adsorbed pure gases or mixtures. The simulation results are presented in Table III for the pure gases and in Table III for the mixtures with pore widths d equal to 1.0 nm and 2.5 nm. The statistical errors on the amount of adsorbed molecules and density profile are estimated equal to 2-3% and 3-5% respectively.

At same temperature and pressure, for pure H_2 , CO_2 and CH_4 the total amounts of adsorbed gases m_a^i , expressed in mole per gram of adsorbent, differ markedly. These dif-

ferences can be quantitatively assessed by computing a selectivity ratio or separation factor S_p^{ij} defined by $S_p^{ij} = m_a^i/m_a^j$. For a pore width d=1.0 nm and pressures from 0 to 5.0 MPa, $S_p^{CO_2,H_2}$ varies between 29 and 6, $S_p^{CO_2,CH_4}$ between 3 and 1.3 and $S_p^{CH_4,H_2}$ between 10 and 4. When d is equal to 2.5 nm, these variations are smaller: between 7 and 5 for $S_p^{CO_2,H_2}$, between 2.9 and 1.5 for $S_p^{CO_2,CH_4}$ and between 4 and 2.7 for $S_p^{CH_4,H_2}$. In addition, when d changes, the variations of ratios S_p^{ij} are different when the pressure increases. Since for the slits of different widths, the pore model keeps an identical adsorption surface, the behaviors of S_p^{ij} must be attributed to the change in the local average density $\rho^i(x)$ (density profile) inside the pore when d is modified.

The typical density profiles of pure gases at pressures of 0.5 and 5.0 MPa are given in Fig. 2 for d equal to 1.0 nm and Fig. 3 for d equal to 2.5 nm. The main characteristics of the profiles are the height and width of the peaks located near the adsorbent surfaces which depend on the interaction strength between adsorbed molecules and adsorbent. Clearly the height of peaks indicates that CO_2 is more strongly adsorbed than H_2 , and also CH_4 , an indication confirming the values of m_a^i in Table II.

For the pore width d=1.0 nm and P_T varying from 0.05 to 5.0 MPa, the adsorption of H_2 increases quasi linearly. The adsorptions of CO_2 and CH_4 , increase fastly between 0.05 and 1.0 MPa, but, above 1.0 MPa, more slowly and seem to go towards an asymptotic maximal value. They correspond to adsorption isotherms of type I [1, 35]. The saturation of the adsorption for these two gases results from intermolecular excluded volume effects appearing in particular near the adsorption surface when the local density $\rho^i(x)$ becomes large. The variations of m_a^i explain, for the slit width d=1.0 nm, the qualitative variations of $S_p^{i,i}$. In particular for $S_p^{CO_2,H_2}$ and $S_p^{CO_2,CH_4}$, the occurrence of a marked maximum at 0.5 MPa results from the fast increase followed by a slow increase for $P_T > 1.0$ MPa of CO_2 and CH_4 adsorptions compared to the linear increase of H_2 adsorption in the domain of pressures $P_T < 5.0$ MPa.

The density profiles, plotted in Fig. 3 for a slit width d=2.5 nm, show that the central part of the slit is filled by a gas having the density of the bulk phase, excepted for CO_2 at 5.0 MPa. The peak widths of $\rho^i(x)$ are equal to $\simeq 0.3$ -0.45 nm and indicate that the adsorbed molecules are localized near the slit walls in the range of the van der Waals interactions between gas molecules and GNF (cf. Table I). The increase of $m_a^{H_2}$ for increasing pressures is linear and that of $m_a^{CH_4}$ also similar to that obtained when d=1.0 nm. But $m_a^{CO_2}$

increases steadily with P_T as consequence of the filling of the central part of the slit by a dense gas which, at 5.0 MPa, has a density almost equal to that of CO_2 liquid phase in equilibrium with the gaseous phase at 293 K, equal to 17.61 mmol/cm³. The isotherm adsorption of CO_2 is of type II [1, 35, 36] and the strong increase of $m_a^{CO_2}$ for $P_T > 3.0$ MPa leads to a capillary condensation at $P_T = 5.0$ MPa, reminding that, at 293 K, the liquid-gas transition in the bulk fluid takes place at 5.709 MPa. Obviously, the quantitative variations of $S_p^{i,j}$ correspond to those of m_a^i . Since the increase of $m_a^{H_2}$ and $m_a^{CH_4}$ with pressure are qualitatively similar to that found when the slit width is equal to 1.0 nm, $S_p^{CH_4,H_2}$ presents a maximum at $P_T \simeq 0.25$ MPa. But, due to the fast increase of $m_a^{CO_2}$ for $P_T > 1.0$ MPa, $S_p^{CO_2,H_2}$ and $S_p^{CO_4,CH_4}$ increase on all the considered domain of pressures.

From the total amount of adsorbed gases m_a^i inside a porous material, it is possible to define the excess adsorption m_e^i by substracting to m_a^i the contribution associated to the filling of the pore network by the gases at their bulk density, this latter contribution remaining present even if the gas-adsorbent attractive interaction was very weak. m_e^i is equal to

$$m_e^i = m_a^i - v_p d_B^i / M_a = m_a^i - m_B^i$$
 (2)

where v_p is the volume of pore network accessible to the adsorbed gas, d_B^i the density of the bulk gas in mole per volume unit and M_a the adsorbent mass. v_p can be experimentally determined by the helium displacement method [37] and, in the numerical simulations, by the procedure described in [38].

The excess adsorptions m_e^i for pure gases H_2 , CO_4 and CH_4 are given in Table II. They show that the values of m_B^i always represent a sizeable part of total amounts of adsorbed gases, but as it is seen from Fig. 4 the selectivities $S_e^{i,j} = m_e^i/m_e^j$ computed from the excess adsorption keep a qualitative behavior similar to those computed with the total adsorption although the values of $S_e^{i,j} = m_e^i/m_e^j$ are larger than those of $S_p^{i,j}$. $S_e^{i,j}$ gives a better estimate of the adsorption and selectivity properties of adsorbent surfaces since, excepted when a capillary condensation takes place, m_e^i corresponds to the gas amount in excess with respect to bulk phase present in the peaks of $\rho^i(x)$ or adsorbed layers located near the slit walls.

The GCMC simulations for binary equimolar mixtures have been performed at 293K for total pressures P_T between 0.1 and 10.0 MPa. The differences between the adsorption of

pure gases and mixtures can be appreciated by comparing the results obtained at identical temperatures for mixtures and pure phases. To be significant this comparison must be performed for states where the partial pressures and chemical potentials of components are equal to those existing in their pure phases. So, by using Table II and III and Figs. 2, 3 and 5 to 8, it is seen that for the CO_2 - H_2 and CH_4 - H_2 mixtures the amount of adsorbed H_2 is generally less than it would be expected from the adsorption of the pure gases.

For instance in the the slit d=1.0, for CO_2 - H_2 mixture at $P_T=1.0$ MPa and $P_{H2}=0.5$ MPa, $m_a^{H_2}$ is equal to 0.09 mmol/gr and equal to 0.166 mmol/gr for pure H_2 at 0.5 MPa. This decrease of $m_a^{H_2}$ is more marked in the same mixture at $P_T=10.0$ MPa and $P_{H2}=5.7$ MPa. The variation of $m_a^{CO_2}$ between the pure gas and mixture is weak and of the order of few percent. Similar variations of $m_a^{H_2}$ and $m_a^{CH_4}$, quantitatively smaller, are found between pure H_2 or pure CH_4 and CH_4 - H_2 mixture. For the CH_4 - CO_2 mixture, both $m_a^{CH_4}$ and $m_a^{CO_2}$ present important variations between the adsorptions of mixture and pure gases.

When d=2.5, at $P_T=1.0$ MPa for the mixtures and $P_T\simeq 0.5$ MPa for the pure gases, the central part of the slit is filled by the bulk mixtures or gases. In spite of the strong localization of adsorbed molecules on adsorbent surface, the superficial density of adsorbed molecules stays low and no excluded volume effect between molecules precludes each mixture component to be adsorbed independently, so that for CO_2 - H_2 mixture, $m_a^{H_2}$ and $m_a^{CO_2}$ are equal to 0.3 and 1.84 mmol/gr and for pure gases to 0.32 and 1.82 mmol/gr. Similar results are obtained for the other mixtures and are in full agreement with the quasi identity of the density profiles in mixtures and pure gases (cf. Fig. 3 and 6).

When the pressure increases this agreement between the adsorptions and density profiles of pure gase and mixtures disappears. At $P_T = 10.0$ MPa, $\rho^{H_2}(x)$ differs in CO_2 - H_2 and CH_4 - H_2 mixtures, and these two profiles differ from that found for the pure gas at 5.0 MPa. The $m_a^{H_2}$ values also differ and are respectively 1.26 and 2.42 mmol/gr for the CO_2 - H_2 and CH_4 - H_2 mixtures and 2.99 mmol/gr for the pure gas. At $P_T = 10.0$ MPa, $\rho^{CH_4}(x)$ in CH_4 - CO_2 mixture differs strongly from CH_4 density profile in pure gas at 5.0 MPa, since the large CH_4 - CO_2 van der Waals interactions leads to the filling of the slit central part by a dense CH_4 - CO_2 mixture (capillary condensation), with relative composition 35 - 65 %. As in pure CO_2 , the capillary condensation is also presents in CO_2 - H_2 mixture. Only $\rho^{CH_4}(x)$ in the CH_4 - H_2 mixture stays almost idenditical to the density profile in pure gas, the H_2 adsorption ($m_a^{H_2}$ =2.4 mmol/gr) being smaller than that of CH_4 ($m_a^{CH_4}$ =7.3 mmol/gr).

Similarly to the case of pure gases, the quantities m_e^i can be defined in the mixtures by using Eq. 2 where d_B^i is the gas density in the bulk mixture. They are plotted in Fig. 9 and 10 for the two considered witdhs of slits and $P_T < 10.0$ MPa. For d = 1.0 nm the excess adsorption isotherms of CO_2 are of type I in CO_2 - H_2 and CO_2 - CH_4 mixtures, that of CH_4 is also of type I in CH_4 - H_2 mixture. The isotherms of H_2 differ strongly of the type I in CO_2 - H_2 and CH_4 - H_2 mixtures, because when P_T increases, $m_e^{H_2}$ goes to zero and negative values as a consequence of the fact that $m_B^{H_2}$ becomes larger than $m_a^{H_2}$ (cf. H_2 density profiles in Fig. 7). When d = 2.5, the two isotherms of CO_2 in CO_2 - H_2 and CO_2 - CH_4 mixtures are similar to type II isotherms. CH_4 isotherm in CH_4 - H_2 mixture does not reach saturation in the considered domain of P_T . H_2 isotherm in CH_4 - H_2 mixture and CH_4 isotherm in CO_2 - CH_4 have a shape similar to that of the isotherm of type I. In CO_2 - H_2 , $m_e^{H_2}$ goes to zero with increasing pressures as it is expected from the density profile plotted in Fig. 8.

It is important to mention that the existence of capillary condensation in CO_2 pure gas at $P_T = 5.0$ MPa and CO_2 - H_2 mixture at $P_T = 10.0$ MPa is dependent on slit width. This condensation disappears for instance when d = 5.0 nm. As it is seen in Fig. 11, the central part of slit is always occupied by a pure gas or mixture of density and composition equal to that of bulk pure phase or mixture. However, the density profile H_2 in the mixture differs strongly from that found for the pure gas and stays smaller than $d_R^{H_2}$.

From the previous discussion of GCMC adsorption results, it appears that the selectivities computed for mixture can present important differences with those calculated from adsorption data for pure gases. A good agreement is obtained only when the mixture components can be adsorded quasi independently, such conditions are realized in the slit d=1.0 nm at very low pressures $\simeq 0.1$ MPa and slit d=2.5 nm for pressures < 0.5 MPa. For $P_T>1.0$ MPa, $S_p^{i,j}$ and $S_m^{i,j}$ generally disagree in particular for the slit d=1.0 nm where the excluded volume effects play a major role (cf. Table II and III). The simulation results show that the characterics of adsorption process differ qualitatively with the pore size. The determination of the adsorption properties at a macroscopic scale clearly depends on an estimate of pore size distribution of adsorbing materials.

The interpretation of simulation results by theoretical models can be attempted by using,

for instance, the Langmuir approach [1, 39] and the associated excess adsorption isotherm

$$m_e^i = m_{\text{max}}^i \frac{B \, P_T}{1 + B \, P_T} \,.$$
 (3)

The simulation data can be reasonably fitted by the Langmuir isotherm as it is shown in Fig. 12. However the fit is meaningful only when the parameters m_{max}^i and B have values which are physically acceptable. The parameter m_{max}^i in the Langmuir approach corresponds to the maximal density of molecules per unit of adsorbent mass present in the first layer adsorbed on the adsorbent surface. This density is generally estimated to be of the order of magnitude of that of adsorbing sites on the adsorbent surface. In our GNF model, the adsorbing sites are CH groups which have a superficial density of 12.0 per nm² giving a value of $m_{\rm max}^i \simeq 12.5$ mmol/gr. The parameter B can be written $C_a(T) \exp(-E_a/kT)$. E_a is an energy associated to the adsorption of one molecule on the adsorbent surface. The parameter $C_a(T)$, depends on temperature and takes into account the other characteristics of the molecular adsorption [1]. The typical values of E_a , estimated from the minimum of the LJ interactions between molecules and adsorbent are contained between -100 K and -40 K. These estimates give at room temperature $\exp(-E_a/kT) \simeq 1.1 - 1.4$. Clearly independent values of m_{max}^i and B cannot be obtained when the fitted values of B are such as $BP_T \ll 1$ in the considered range of pressures. When $BP_T \ll 1$, the Langmuir isotherm is similar to the Henry's law isotherm since m_e^i becomes proportional to P_T .

The previous remarks lead to conclude that significant values of m_{max}^i and B are obtained from the fit of CO_2 and CH_4 isotherms for d=1.0 nm and that of CH_4 isotherm for d=2.5. For these 3 isotherms the values of m_{max}^i are, respectively, equal to 10.1, 7.1 and 10.4 and those of B equal to 1.6, 0.6 and 0.2 when P_T is expressed in MPa. The values of m_{max}^i are in a reasonable agreement with the estimate made from the superficial density of CH groups.

The fit of the linear isotherms of H_2 for d=1 and 2.5 nm gives obviously $BP_T << 1$., but the products $m_{\rm max}^i B$ have almost identical values 0.19 and 0.21 as it is expected when the adsorption isotherms depend only on the Henry's law constant. The isotherm of CO_2 at d=2.5 nm is also quasi linear, but the fit cannot be considered as physically significant since the increase of m_i^e for $P_T > 3.0$ MPa is due to the capillary condensation which is not described by the Langmuir theoretical approach.

The Langmuir isotherm for the component i of a mixture with n components is given by

$$m_e^i = m_{\text{max}}^i \frac{B_i P_i}{1 + \sum_{j=1,n} B_j P_j} \,. \tag{4}$$

Since the parameter B_i must be positive m_e^i being positive at low pressures, and the partial pressures P_i are monotonic increasing function of P_T , the Langmuir isotherm does not show a maximun and is not convenient to represent the adsorption isotherms of H_2 in the H_2 - CO_2 mixture, for d=1.0 and 2.5 nm, and H_2 - CH_4 mixture, for d=1.0 nm, where $m_e^{H_2}$ decreases when the partial pressures increase. For an identical reason, the isotherm of CH_4 for d=1.0 nm cannot be described by a Langmuir isotherm. The occurrence of a capillary condensation precludes the use of the Langmuir isotherms for describing the adsorption of CO_2 - CH_4 mixture when d=2.5 nm. A fit of the adsorption of H_2 - CH_4 mixture for d=2.5 nm by the Langmuir isotherms is possible as it is shown in Fig. 10. This result agrees with the density profiles of H_2 and CH_4 plotted in Fig. 6 and 8 which, in accordance with the Langmuir approach hypotheses, correspond to mono-layers of adsorbed molecules in equilibrium with the gas bulk phase.

IV. CONCLUSION

The analysis of the GCMC simulation results of the adsorption of pure gases and binary mixtures in a pore model of GNF shows the diversity of the adsorption processes which are induced by the interplay between properties of adsorbent surface and pore sizes. From the range of the van der Waals interactions, it results that the adsorbed molecules are located in a layer having an extent smaller than 0.5 nm (0.3-0.45 nm) as it is seen in Figs. 2, 3 and 5-8. In pores of small size ($\simeq 1.0$ nm), the localization of adsorbed molecules near pore surfaces and excluded volume effects between molecules leads for the gases having a strong interaction with the adsorbent to the saturation of the adsorption at high pressures. In pore of size equal 2.0-3.0 nm, at $\simeq 5.0-10.0$ MPa, the layer of adsorbed molecules of gases strongly interacting with adsorbent becomes dense. The gas molecules which interact with this dense layer of adsorbed molecules induce the onset of a second layer (cf. CH_4 profile Fig. 3) or generate a capillary condensation (cf. CO_2 profile Fig. 3). In this latter case the isotherm adsorption is similar to an isotherm of type II.

These different adsorption processes also exist in the mixtures. For the binary mixtures considered in this work, the main feature is that the adsorption of gas interacting the most strongly with adsorbent can preclude the adsorption of the other component. The adsorption depletion of the weakly interacting gas is manifest from H_2 profiles in Fig. 7 and 8. In

particular, the depletion is strong when a capillary condensation occurs. The main consequence of this result is that the selectivities computed from the adsorption data of pure gases can be a poor estimate of the selectivities in the mixtures. The simulation data clearly show that the adsorption and separation properties of a porous material at a macroscopic scale result from adsorption processes which, at a microscopic scale, differ markedly in particular with the pore size and pressure. This fact should be taken into account in the choice of the most adequate material for perfoming the separation of mixture components at a given thermodynamic state.

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Figure Captions

- Fig. 1. Snapshot of H_2 CO_2 mixture in the simulation cell of sides $L_y = 4.18$ nm and $L_z = 5.36$ nm with a slit of width d = 2.5 nm and stack lateral extent D = 1.1 nm in the x-direction, at 293 K and pressure of 10.0 MPa. Blue dots: H_2 molecule, green dots: CO_2 molecule, yellow dots CH group. The red lines link next neighborings C atoms or CH groups in a graphene sheet
- Fig. 2. Adsorption density profiles (filled circle and dashed-line) of pure gases (mmol/cm^3) in a slit of width d = 1.0 nm at 293 K for pressures of 0.5 MPa (left column) and 5.0 MPa (right column), from top to bottom H_2 , CO_2 and CH_4 . Horizontal dashed lines: bulk density of gases.
- Fig. 3. Adsorption density profiles (filled circle and dashed-line) of pure gases (mmol/cm^3) in a slit of width d = 2.5 nm at 293 K for pressures of 0.5 MPa (left column) and 5.0 MPa (right column), from top to bottom H_2 , CO_2 and CH_4 . Horizontal dashed lines: bulk density of gases.
- Fig. 4. Selectivity $S_e^{i,j}$ as defined in Sect. III for pures gases at 293 K versus pressure (MPa) in a slit of width d = 1.0 nm (bottom) and 2.5 nm (top) : $S_e^{CO_2, H_2}$ filled black circle and dashed line, $S_e^{CH_4, H_2}$ filled red square and dashed line, $S_e^{CO_2, CH_4}$ filled green diamond and dashed line.
- Fig. 5. Adsorption density profiles of components (filled circle and dashed-line) of equimolar binary mixtures (mmol/cm³) in a slit of width d = 1.0 nm at 293 K for a pressure of 1.0 MPa. From top to bottom, H_2 - CO_2 mixture: left column H_2 density profile and right column CO_2 density profile; CH_4 - CO_2 mixture: left column CH_4 density profile and right column CO_2 density profile; H_2 - CH_4 mixture: left column H_2 density profile and right column CH_4 density profile. Horizontal dashed lines: bulk density of mixture components.
- Fig. 6. Adsorption density profiles of components (filled circle and dashed-line) of equimolar binary mixtures (mmol/cm³) in a slit of width d = 2.5 nm at 293 K for a pressure of 1.0 MPa. From top to bottom, H_2 - CO_2 mixture: left column H_2 density profile and right column CO_2 density profile; CH_4 - CO_2 mixture: left column CH_4 density profile and right column CO_2 density profile; H_2 - CH_4 mixture: left column H_2 density profile and right column CH_4 density profile. Horizontal dashed lines: bulk density of mixture components.
- Fig. 7. Adsorption density profiles of components (filled circle and dashed-line) of equimolar binary mixtures (mmol/cm³) in a slit of width d = 1.0 nm at 293 K for a pressure of

- 10.0 MPa. From top to bottom, H_2 - CO_2 mixture: left column H_2 density profile and right column CO_2 density profile; CH_4 - CO_2 mixture: left column CH_4 density profile and right column CO_2 density profile; H_2 - CH_4 mixture: left column H_2 density profile and right column CH_4 density profile. Horizontal dashed lines: bulk density of mixture components.
- Fig. 8. Adsorption density profiles of components (filled circle and dashed-line) of equimolar binary mixtures (mmol/cm³) in a slit of width d = 2.5 nm at 293 K for a pressure of 10.0 MPa. From top to bottom, H_2 - CO_2 mixture: left column H_2 density profile and right column CO_2 density profile; CH_4 - CO_2 mixture: left column CH_4 density profile and right column CO_2 density profile; H_2 - CH_4 mixture: left column H_2 density profile and right column CH_4 density profile. Horizontal dashed lines: bulk density of mixture components.
- Fig. 9. Excess adsorption m_e^i for binary mixtures in a slit of width d=1.0 nm at 293 K versus pressure (MPa). From top to bottom H_2 - CO_2 mixture: left column blue circles and dashed line H_2 , right column red circles and dashed line CO_2 ; H_2 - CH_4 mixture: left column blue squares and dashed line H_2 , right column green squares and dashed line CH_4 , CH_4 - CO_2 mixture: left column green diamonds and dashed line CH_4 , right column red diamonds and dashed line CO_2 .
- Fig. 10. Excess adsorption m_e^i for binary mixtures in a slit of width d=2.5 nm at 293 K versus pressure (MPa). From top to bottom H_2 - CO_2 mixture: left column blue circles and dashed line H_2 , right column red circles and dashed line CO_2 ; H_2 - CH_4 mixture: left column blue squares and dashed line H_2 , right column green squares and dashed line CH_4 , black dashed-line fit by a Langmuir isotherm; CH_4 - CO_2 mixture: left column green diamonds and dashed line CH_4 , right column red diamonds and dashed line CO_2 .
- Fig. 11. At 293 K in a slit of width d = 5.0 nm adsorption density profiles (mmol/cm³): top, at $P_T = 5.0$ MPa, right column pure H_2 (filled blue circle and dashed line) and left column pure CO_2 (filled red circle and dashed line), bottom, at $P_T = 10.0$ MPa, components of H_2 - CO_2 equimolar mixture filled blue circle and dashed line H_2 and filled red circle and dashed line CO_2 . Horizontal dashed lines: bulk density of pure gases and mixture components.
- Fig. 12. Excess adsorption m_e^i (mmol/gr) versus pressure (MPa) at 293 K for pure gases in slits of width d = 1.0 nm (left column) and 2.5 nm (right column). Dashed-dotted line fit by a Langmuir isotherm of GCMC data, filled circle : H_2 , filled square : CO_2 and filled diamond : CH_4 .

Table Captions

Table I. Parameter ϵ (degree K) and σ (Å) of LJ potentials of gas molecules and GNF C atoms or CH chemical groups. l (Å) distance to molecule center of mass along the symmetry molecular axis of the effective charges q (unit of electron charge) associated to H_2 and CO_2 quadrupoles.

Table II. Adsorption of pure gases. P_T total pressure (MPa), d_B bulk density of gases (mmol/cm³), m_a^i and m_e^i total and excess adsorption (mmol/gr), $S_p^{i,j}$ selectivity. Column 3, 4 and 5 results for a slit of width d = 1.0 nm, column 6, 7 and 8 results for a slit of width d = 2.5 nm.

Table III. Adsorption of binary equimolar mixtures. P_T total pressure (MPa). Column 2 and 3 partial pressure of mixture components (MPa). Column 4, 5 and 6: total adsorption of mixture components (mmol/gr) and selectivity for a slit of width d = 1.0 nm. Column 7, 8 and 9 total adsorption of mixture components (mmol/gr) and selectivity for a slit of width d = 2.5 nm.

TABLE I:

Atom/Molecule	ϵ	σ	q	l
H_2	36.7	2.958	0.483	0.3705
CH_4	148.2	3.817	-	-
O_{CO_2}	79.0	3.05	-0.35	1.160
C_{CO_2}	27.0	2.80	0.70	0.00
C_{GNF}	28.0	3.400	-	-
CH_{GNF}	46.0	3.770		_

TABLE II:

H_2									
P_T	d_B	$m_a^{H_2}$	$m_e^{H_2}$	$S_p^{CO_2,H_2}$	$m_a^{H_2}$	$m_e^{H_2}$	$S_p^{CO_2,H_2}$		
0.05	0.020	0.021	0.014	14.2	0.037	0.016	5.8		
0.25	0.103	0.084	0.050	21.7	0.163	0.059	5.8		
0.5	0.205	0.167	0.098	29.6	0.322	0.114	5.8		
1.5	0.603	0.477	0.270	16.7	0.892	0.281	6.9		
2.6	1.091	0.846	0.473	10.2	1.67	0.565	6.2		
4.9	1.989	1.48	0.808	6.1	2.99	0.976	7.9		
	CO_2								
P_T	d_B	$m_a^{CO_2}$	$m_e^{CO_2}$	$S_p^{CO_2,CH_4}$	$m_a^{CO_2}$	$m_e^{CO_2}$	$S_p^{CO_2,CH_4}$		
0.05	0.020	0.299	0.292	1.8	0.214	0.194	1.7		
0.25	0.103	1.82	1.79	2.1	0.944	0.839	1.5		
0.5	0.205	4.94	4.87	2.9	1.88	1.67	1.6		
1.5	0.663	7.99	7.76	1.9	6.17	5.49	1.9		
2.5	1.168	8.60	8.20	1.7	10.4	9.21	2.1		
4.9	2.834	9.13	8.16	1.4	23.5	20.64	2.9		
	CH_4								
P_T	d_B	$m_a^{CH_4}$	$m_e^{CH_4}$	$S_p^{CH_4,H_2}$	$m_a^{CH_4}$	$m_e^{CH_4}$	$S_p^{CH_4,H_2}$		
0.05	0.020	0.166	0.160	7.9	0.124	0.104	3.4		
0.24	0.103	0.864	0.831	10.3	0.618	0.538	3.8		
0.49	0.205	1.68	1.62	10.1	1.18	0.984	3.7		
1.5	0.603	4.11	3.90	8.6	3.29	2.65	3.7		
2.6	1.059	5.20	4.84	6.2	4.92	4.81	2.9		
5.5	2.265	6.40	5.63	4.3	8.18	5.88	2.7		

TABLE III:

$H_2 - CO_2$ Mixture									
P_T	P_{H_2}	P_{CO_2}	$m_a^{H_2}$	$m_a^{CO_2}$	$S_m^{CO_2,H_2}$	$m_a^{H_2}$	$m_a^{CO_2}$	$S_m^{CO_2,H_2}$	
0.1	0.05	0.05	0.02	0.26	13.0	0.04	0.22	5.5	
0.5	0.25	0.25	0.07	1.62	23.1	0.15	0.90	6.0	
1.0	0.5	0.5	0.09	4.69	52.1	0.30	1.84	6.1	
2.9	1.5	1.4	0.09	7.81	86.8	0.76	5.53	7.3	
5.0	2.6	2.4	0.11	8.45	76.8	1.17	9.17	7.8	
10.1	5.7	4.4	0.18	8.92	49.6	1.26	20.5	16.3	
	$H_2 - CH_4$ Mixture								
P_T	P_{H_2}	P_{CH_4}	$m_a^{H_2}$	$m_a^{CH_4}$	$S_m^{CH_4,H_2}$	$m_a^{H_2}$	$m_a^{CH_4}$	$S_m^{CH_4,H_2}$	
0.1	0.05	0.05	0.020	0.169	8.5	0.044	0.169	3.8	
0.5	0.25	0.25	0.090	0.841	9.3	0.161	0.624	3.9	
1.0	0.5	0.5	0.144	1.65	11.5	0.310	1.19	3.8	
3.0	1.5	1.5	0.299	3.92	13.1	0.860	3.14	3.7	
5.0	2.5	2.5	0.391	4.94	12.6	1.35	4.63	3.4	
10.0	5.0	5.0	0.712	5.97	8.4	2.42	7.30	3.0	
	$CH_4 - CO_2$ Mixture								
P_T	P_{CO_2}	P_{CH_4}	$m_a^{CH_4}$	$m_a^{CO_2}$	$S_m^{CO_2,CH_4}$	$m_a^{CH_4}$	$m_a^{CO_2}$	$S_m^{CO_2,CH_4}$	
0.1	0.05	0.05	0.253	0.389	1.5	0.176	0.255	1.4	
0.5	0.25	0.25	0.961	2.15	2.2	0.718	0.929	1.3	
1.0	0.5	0.5	1.40	3.87	2.8	1.16	1.85	1.6	
3.0	1.6	1.4	1.33	5.87	4.4	2.74	5.17	1.9	
5.0	2.7	2.3	1.58	6.59	4.2	3.88	7.96	2.0	
10.2	5.88	4.36	1.71	6.95	4.1	5.64	13.3	2.4	























